

NPN Silicon General Purpose Amplifier Transistor

2SC4617G, S2SC4617G

This NPN transistor is designed for general purpose amplifier applications. This device is housed in the SC-75/SOT-416 package which is designed for low power surface mount applications, where board space is at a premium.

Features

- Reduces Board Space
- High h_{FE}, 210-460 (typical)
- Low $V_{CE(sat)}$, < 0.5 V
- Available in 8 mm, 7 inch/3000 Unit Tape and Reel
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant*

MAXIMUM RATINGS (T_{.1} = 25°C)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V _{(BR)CBO}	50	Vdc
Collector-Emitter Voltage	V _{(BR)CEO}	50	Vdc
Emitter-Base Voltage	V _{(BR)EBO}	5.0	Vdc
Collector Current - Continuous	Ic	100	mAdc

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

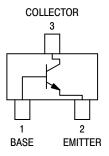
Characteristic	Symbol	Max	Unit
Power Dissipation (Note 1)	P_{D}	125	mW
Junction Temperature	TJ	150	°C
Storage Temperature Range	T _{stg}	−55 ~ +150	°C

1. Device mounted on a FR-4 glass epoxy printed circuit board using the minimum recommended footprint.

NPN GENERAL PURPOSE AMPLIFIER TRANSISTORS SURFACE MOUNT



CASE 463-01 STYLE 1



MARKING DIAGRAM



= Device Code = Date Code* = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
2SC4617G	SC-75 (Pb-Free)	3,000/Tape & Reel
S2SC4617G	SC-75 (Pb-Free)	3,000/Tape & Reel
2SC4617T1G	SC-75 (Pb-Free)	3,000/Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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^{*}For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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ELECTRICAL CHARACTERISTICS (T_A = 25°C)

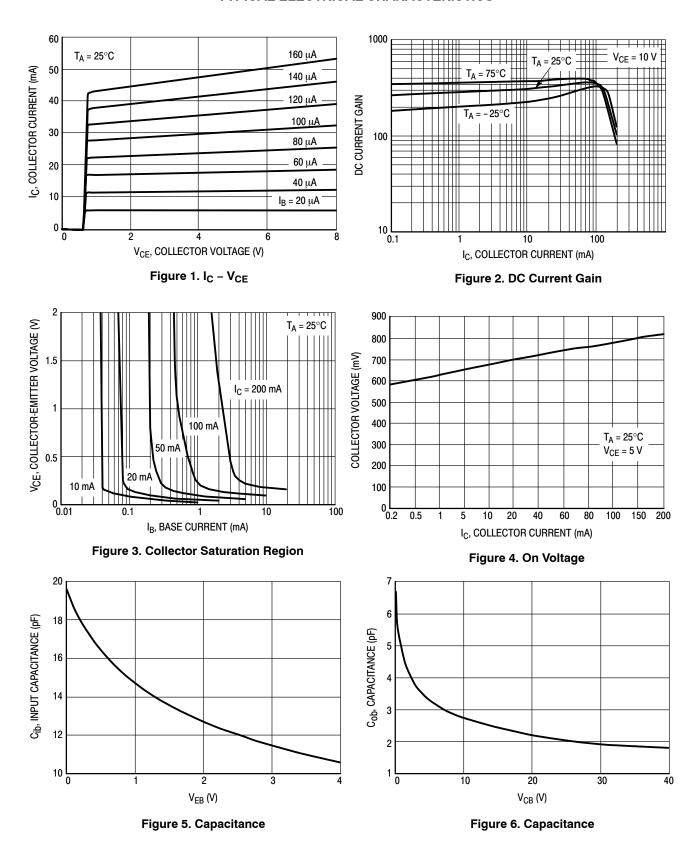
Characteristic	Symbol	Min	Тур	Max	Unit
Collector-Base Breakdown Voltage (I _C = 50 μAdc, I _E = 0)	V _{(BR)CBO}	50	-	-	Vdc
Collector-Emitter Breakdown Voltage (I _C = 1.0 mAdc, I _B = 0)	V _{(BR)CEO}	50	_	-	Vdc
Emitter-Base Breakdown Voltage (I _E = 50 μAdc, I _E = 0)	V _{(BR)EBO}	5.0	_	-	Vdc
Collector-Base Cutoff Current (V _{CB} = 30 Vdc, I _E = 0)	I _{CBO}	-	-	0.5	μΑ
Emitter-Base Cutoff Current (V _{EB} = 4.0 Vdc, I _B = 0)	I _{EBO}	-	-	0.5	μΑ
Collector-Emitter Saturation Voltage (Note 2) (I _C = 60 mAdc, I _B = 5.0 mAdc)	V _{CE(sat)}	-	-	0.4	Vdc
DC Current Gain (Note 2) (V _{CE} = 6.0 Vdc, I _C = 1.0 mAdc)	h _{FE}	120	-	560	-
Transition Frequency (V _{CE} = 12 Vdc, I _C = 2.0 mAdc, f = 30 MHz)	f _T	-	180	-	MHz
Output Capacitance (V _{CB} = 12 Vdc, I _C = 0 Adc, f = 1 MHz)	C _{OB}	-	2.0	-	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

^{2.} Pulse Test: Pulse Width \leq 300 μ s, D.C. \leq 2%.

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TYPICAL ELECTRICAL CHARACTERISTICS





SC75-3 1.60x0.80x0.80, 1.00P

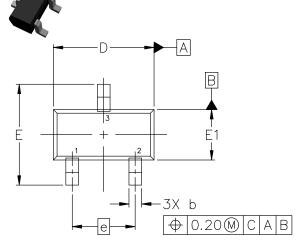
CASE 463 ISSUE H

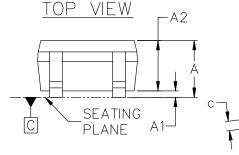
DATE 01 FEB 2024

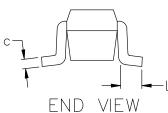


- 1. DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
- 2. ALL DIMENSION ARE IN MILLIMETERS.

DIM	MILLIMETERS			
DIM	MIN.	NOM.	MAX.	
А	0.70	0.80	0.90	
A1	0.00	0.05	0.10	
A2	0.80 REF.			
b	0.15	0.20	0.30	
С	0.10	0.15	0.25	
D	1.55	1.60	1.65	
Е	1.50	1.60	1.70	
E1	0.70	0.80	0.90	
е	1.00 BSC			
L	0.10	0.15	0.20	







SIDE VIEW

GENERIC MARKING DIAGRAM*



XX = Specific Device Code

M = Date Code

= Pb-Free Package

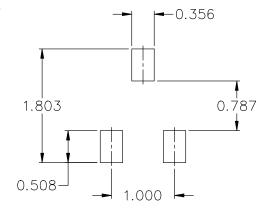
*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1:	
PIN 1. BASE	
O ENTITED	

1. BASE 2. EMITTER 3. COLLECTOR STYLE 2: PIN 1. ANODE 2. N/C 3. CATHODE STYLE 3: PIN 1. ANODE 2. ANODE 3. CATHODE FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES

REFERENCE MANUAL, SOLDERRM/D.

RECOMMENDED MOUNTING FOOTPRINT*



 STYLE 4:
 STYLE 5:

 PIN 1. CATHODE
 PIN 1. GATE

 2. CATHODE
 2. SOURCE

 3. ANODE
 3. DRAIN

DOCUMENT NUMBER:

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DESCRIPTION: SC75-3 1.60x0.80x0.80, 1.00P

98ASB15184C

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